VSLY5940

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Vishay Semiconductors

High Speed Infrared Emitting Diode, 940 nm, Surface Emitter Technology



As part of the <u>SurfLight</u>[™] portfolio, the VSLY5940 is an infrared, 940 nm emitting diode based on GaAlAs surface

emitter chip technology with extreme high radiant intensity,

high optical power and high speed, molded in a clear,

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Leads with stand-off
- Peak wavelength: $\lambda_p = 940 \text{ nm}$
- High reliability
- High radiant power
- High radiant intensity
- Narrow angle of half intensity: $\phi = \pm 3^{\circ}$
- Suitable for high pulse current operation
- Good spectral matching with CMOS cameras
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- Smoke-automatic fire detectors
- IR Flash

PRODUCT SUMMARY

DESCRIPTION

COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)
VSLY5940	600	± 3	940	10

Note

Test conditions see table "Basic Characteristics"

untinted plastic package, with a parabolic lens.

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSLY5940	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾	
VSLY5940-CS21	Reel	MOQ: 5000 pcs, 1000 pcs/bulk	T-1¾	

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	A	
Power dissipation		Pv	190	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	$t \leq 5$ s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W	

Rev. 1.2, 29-May-15

1 For technical questions, contact: <u>emittertechsupport@vishay.com</u> Document Number: 84240

Pb e3 RoHS

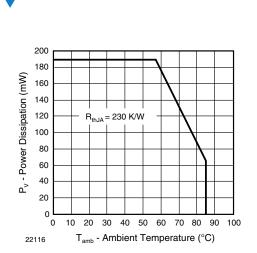
COMPLIANT HALOGEN

FREE

GREEN

(5-2008)

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Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

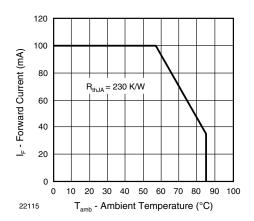


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.65	1.9	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.9		V
Temperature coefficient of V_{F}	I _F = 1 mA	TK _{VF}		-1.45		mV/K
	I _F = 10 mA	TK _{VF}		-1.25		mV/K
Reverse current		I _R	not designed for reverse operation		μA	
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		125		pF
	I _F = 100 mA, t _p = 20 ms	Ι _e	300	600	900	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	Ι _e		5100		mW/sr
Radiant power	I _F = 100 mA, t _p = 20 ms	φ _e		55		mW
Temperature coefficient of ϕ_{e}	l _F = 100 mA	TKφe		-0.35		%/K
Angle of half intensity		φ		± 3		deg
Peak wavelength	l _F = 100 mA	λρ	920	940	960	nm
Spectral bandwidth	l _F = 100 mA	Δλ		35		nm
Temperature coefficient of λ_p	l _F = 100 mA	ΤΚλρ		0.25		nm/K
Rise time	I _F = 100 mA	t _r		10		ns
Fall time	I _F = 100 mA	t _f		10		ns



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

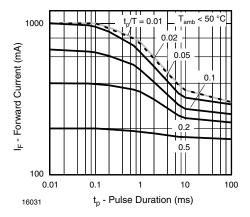


Fig. 3 - Pulse Forward Current vs. Pulse Duration

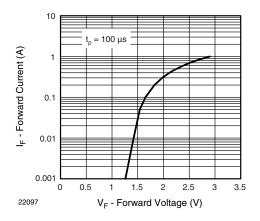


Fig. 4 - Forward Current vs. Forward Voltage

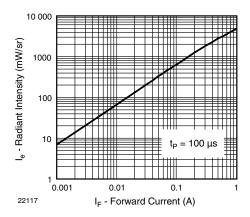


Fig. 5 - Radiant Intensity vs. Forward Current

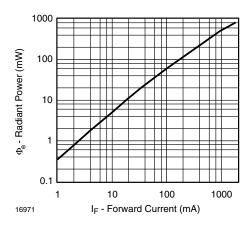


Fig. 6 - Radiant Power vs. Forward Current

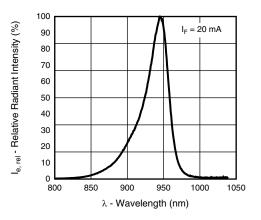


Fig. 7 - Relative Radiant Power vs. Wavelength

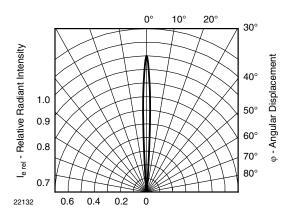


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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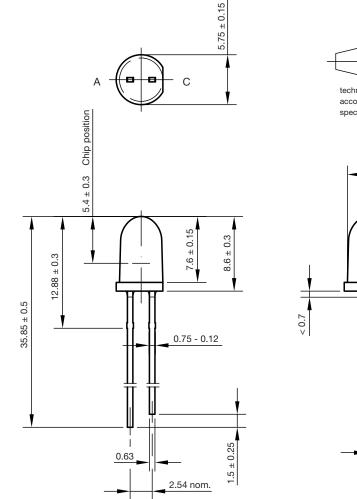
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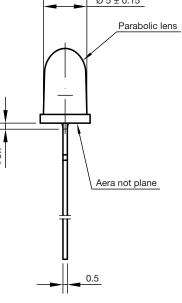
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PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5385.01-4 Issue: 2; 08.03.10 20531 technical drawings according to DIN specifications 0.5 ± 0.15 Parabolic ler



Not indicated tolerances ± 0.1



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